Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Glass

## Overall Length:

Between 0.140 inches and 0.195 inches

## Terminal Length:

Between 0.900 inches and 1.300 inches

## **Overall Diameter:**

Between 0.135 inches and 0.185 inches

## Function For Which Designed:

Transient suppressor

## Mounting Method:

Terminal

Features Provided:

Hermetically sealed case and quality assurance level tx

## Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

11.55 breakdown voltage, dc

### Voltage Tolerance In Percent:

-5.0/+5.0

### **Current Rating Per Characteristic:**

125.00 milliamperes forward current, average horsepower metric and 20.00 microamperes forward current, average peak

### **Power Rating Per Characteristic:**

1500.0 watts small-signal input power, common-collector major

### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### Terminal Type And Quantity:

2 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/516 government specification

#### Shelf Life:

N/a

### Unit Of Measure:

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#### Demilitarization:

No

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